OP505, OP505W, OP506, OP506W OP535, OP705

Electronics

Features:

- T-1 package style
- · Variety of sensitivity ranges
- Choice of narrow or wide receiving angle
- Small package size ideal for space-limited applications
- 0.050" [1.27mm] or 0.100" [2.54mm] Lead spacing



Description:

Each OP505 and OP506 devices consist of an NPN silicon phototransistor, the OP535 device consist of an NPN silicon photodarlington transistor and the OP705 device consist of an NPN silicon phototransistor with a large value resistor integrated between the Base and Emitter for low light signal rejection. All of the devices are molded in a blue-tinted T-1 (3mm) epoxy package

The OP505, OP535 and OP70**5** devices have a narrow receiving angle that provides excellent on-axis coupling while the OP506 device has a wider receiving angle for those applications where a narrow receiving angle of the OP505, OP535 and OP705 is not required. The OP505W and OP506W device have the widest receiving angle and provides relatively even reception over a large area.

Devices are 100% production tested, using infrared light for close correlation with Optek's GaAs and GaAlAs emitters.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Please see your OPTEK representative for custom versions of these devices.

Applications:

- Space-limited applications
- Interruptive applications to detect media which is semitransparent to infrared light

| Ordering Information | | | | | | |
|----------------------|-------------------------------|------------------|---------------------|--------------------|--|--|
| Part Number | Sensor | Viewing Angle | Lead Spacing | Lead Length | | |
| OP505A | | | | 0.50" [12.7 mm] | | |
| OP505B | | 20° | | | | |
| OP505C | | 20 | 0.050" [1.27 mm] | | | |
| OP505D | | | [1.27 11111] | | | |
| OP505W | Transistor | 90° | | | | |
| OP506A | | | | | | |
| OP506B | | 20° | 0.100" | | | |
| OP506C | | | [2.54 mm] | | | |
| OP506W | | 90° | | | | |
| OP535A | Darlington | | | | | |
| OP535B | Darlington | 20° | 0.050" [1.27 mm] | | | |
| OP705A | R _{BE} Transistor | 20 | | | | |

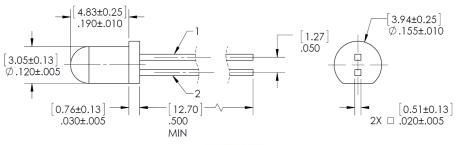


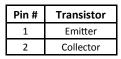
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OP505, OP505W, OP506, OP506W OP535, OP705

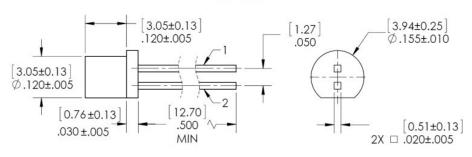


OP505, OP535, OP705





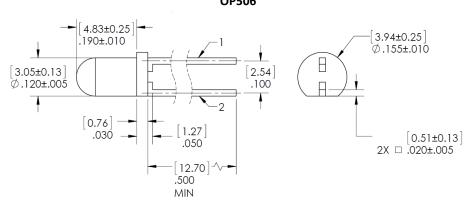
OP505W



OP505, OP506 OP505W, OP506W



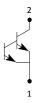
OP506



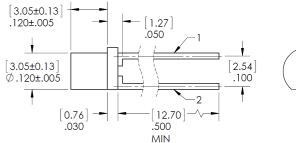
OP705

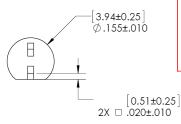


OP535



OP506W





CONTAINS POLYSULFONE

Methanol and isopropanol alcohols are recommended cleaning agents.
Housings are soluble in chlorinated hydrocarbons and keytones.
Highly activated or water soluble fluxes may damage body.
Testing reagents before use is recommended prior to use.

TOLERANCES ARE \pm .010" [.25] UNLESS OTHERWISE STATED DIMENSIONS ARE IN INCHES [MILLIMETERS]

OP505, OP505W, OP506, OP506W OP535, OP705



Electrical Specifications

| Absolute Maximum Ratings (T _A = 25° C unless otherwise noted) | |
|---|-----------------------|
| Storage & Operating Temperature Range | -40°C to +100° C |
| Collector-Emitter Voltage (OP505, OP506, OP505W, OP506W, OP705) | 30 V |
| Collector-Emitter Voltage (OP535) | 15 V |
| Emitter-Collector Voltage (OP505 and OP506 series only) | 5.0 V |
| Lead Soldering Temperature (1/16 inch (1.6 mm) from case for 5 seconds with soldering iron) | 260° C |
| Power Dissipation | 100 mW ⁽²⁾ |
| Emitter Reverse Current (OP705 series only) | 10 mA |
| Collector DC Current (OP705 series only) | 30 mA |

Electrical Characteristics (T_A = 25° C unless otherwise noted) **OP505, OP506, OP505W, OP506W, OP705**

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS | |
|----------------------|--|------|------|-------|--------------------|--|--|
| I _{C(ON)} | On-State Collector Current | | | | | | |
| | OP505A, OP506A | 4.30 | - | - | | _ | |
| | OP505B, OP506B | 2.15 | - | 5.95 | mA | $V_{CE} = 5 \text{ V}, E_e = 0.50 \text{ mW/cm}^2, \text{ Note 3}$ | |
| | OP505C, OP506C | 1.10 | - | 3.00 | | | |
| | OP505D | 0.55 | - | - | | | |
| | OP705A | 3.95 | - | 12.00 | mA | $V_{CE} = 5 \text{ V}, E_e = 0.50 \text{ mW/cm}^2, \text{ Note 3}$ | |
| | OP505W, OP506W | 0.10 | - | - | mA | $V_{CE} = 5 \text{ V}, E_e = 0.75 \text{ mW/cm}^2, \text{ Note 3}$ | |
| V _{CE(SAT)} | Collector-Emitter Saturation Voltage OP505, OP506, OP705 | - | - | 0.40 | V | $I_C = 250 \mu A, E_E = 0.5 \text{ mW/cm}^2, \text{ Note 3}$ | |
| | OP505W, OP506W | - | - | 0.40 | V | $I_C = 50 \mu A$, $E_E = 0.75 \text{ mW/cm}^2$, Note 3 | |
| I _{CEO} | Collector-Dark Current | - | - | 100 | nA | V _{CE} = 10 V, E _E = 0 | |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | 30 | - | - | V | I _C = 100 μA, E _E = 0 | |
| V _{(BR)ECO} | Emitter-Collector Breakdown Voltage OP505, OP506 | 5 | - | | V | I _E = 100 μA, E _E = 0 | |
| | OP705 | 0.4 | - | - | V | I _E = 100 μA, E _E = 0 | |
| ΔΙ _C /ΔΤ | Relative I _C Changes with Temperature | - | 1.00 | - | % / °C | $V_{CE} = 5 \text{ V, } E_E = 1.0 \text{ mW/cm}^2$ | |
| E _{KP} | Knee Point Irradiance (OP705) | - | 0.02 | - | mW/cm ² | V _{CE} = 5 V, Note 4 | |

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
- (2) Derate linearly 1.33 mW/° C above 25° C.
- (3) Light source is an unfiltered GaAs LED with a peak emission wavelength of 935 nm and a radiometric intensity level, which varies less than 10% over the entire lens surface of the phototransistor being tested.
- (4) The knee point irradiance is defined as the irradiance required to increase Ic(on) to 50 μ A.

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OP505, OP505W, OP506, OP506W OP535, OP705



Electrical Specifications

| Electrical Characteristics (T _A = 25° C unless otherwise noted) OP535 | | | | | | |
|--|--|------|-----|------|-------|--|
| SYMBOL | PARAMETER | MIN | ТҮР | МАХ | UNITS | TEST CONDITIONS |
| I _{C(ON)} | On-State Collector Current OP535A OP535B | | - | 32.0 | mA | V _{CE} = 5 V, E _E = 0.13 mW/cm ² , Note 3 |
| V _{CE(SAT)} | Collector-Emitter Saturation Voltage | - | - | 1.10 | V | $I_C = 400 \mu A, E_E = 0.13 \text{ mW/cm}^2$, Note 3 |
| I _{CEO} | Collector-Dark Current | - | - | 100 | nA | V _{CE} = 10 V, E _E = 0 |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | 15.0 | - | - | V | I _C = 1.0 mA, E _E = 0 |
| V _{(BR)ECO} | Emitter-Collector Breakdown Voltage | 5.0 | - | - | V | Ι _Ε = 100 μΑ, Ε _Ε = 0 |

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OP505, OP505W, OP506, OP506W OP535, OP705

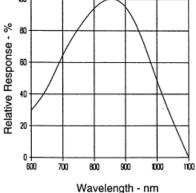


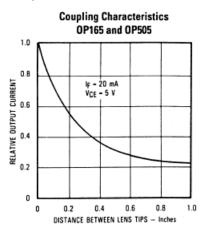
Performance

OP505A, OP505B, OP505C, OP505D

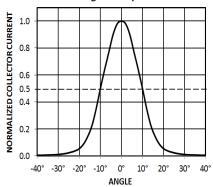


Typical Spectral Response

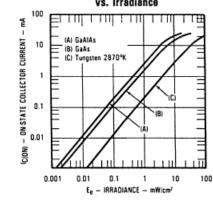




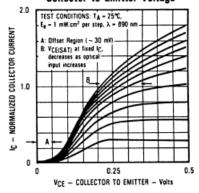
Normalized Collector Current vs. Angular Displacement



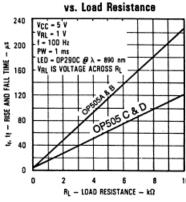
On-State Collector Current vs. Irradiance



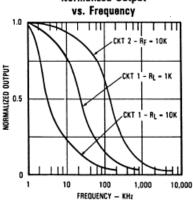
Normalized Collector Current vs. Collector to Emitter Voltage



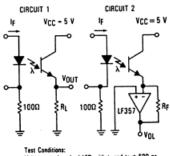
Rise and Fall Time



Normalized Output



Switching Time **Test Circuit**



ght source is pulsed LED with t_f and $t_f \le 500$ ns. is adjusted for $V_{OUT} = 1$ Volt.

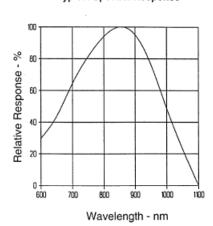
OP505, OP505W, OP506, OP506W OP535, OP705



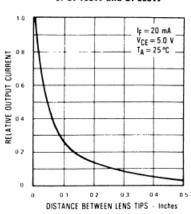
Performance

OP505W

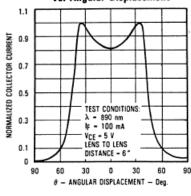
Typical Spectral Response



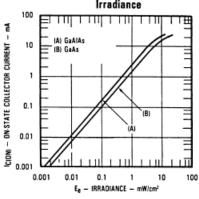
Coupling Characteristics of OP165W and OP505W



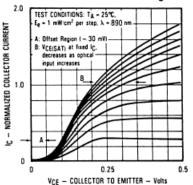
Normalized Collector Current vs. Angular Displacement



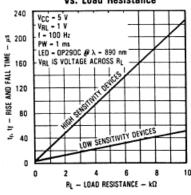
On-State Collector Current vs Irradiance



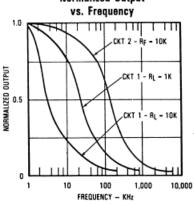
Normalized Collector Current vs. Collector to Emitter Voltage



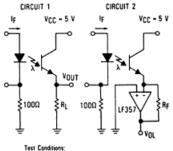
Rise and Fall Time vs. Load Resistance



Normalized Output



Switching Time **Test Circuit**



Light source is pulsed LED with t_r is adjusted for $V_{OUT} = 1$ Volt.

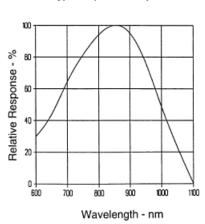
OP505, OP505W, OP506, OP506W OP535, OP705

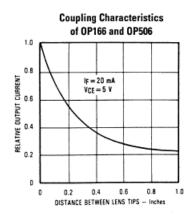


Performance

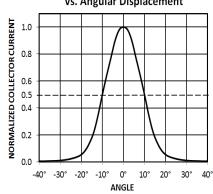
OP506A, OP506B, OP506C



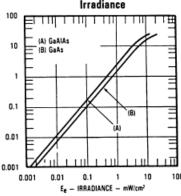




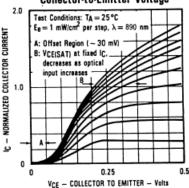
Normalized Collector Current vs. Angular Displacement



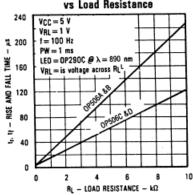
On-State Collector Current vs Irradiance



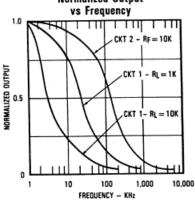
Normalized Collector Current vs Collector-to-Emitter Voltage



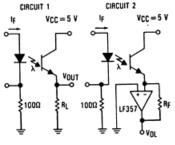
Rise and Fall Time vs Load Resistance



Normalized Output



Switching Time Test Circuit



Test Conditions: Light source is pulsed LED with t_f and $t_f \leq 500$ ns. IF is adjusted for VQUT = 1 Volt.

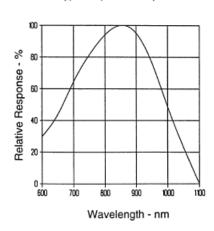
OP505, OP505W, OP506, OP506W OP535, OP705



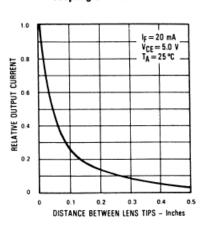
Performance

OP506W

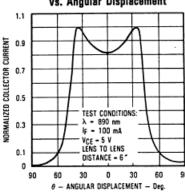
Typical Spectral Response



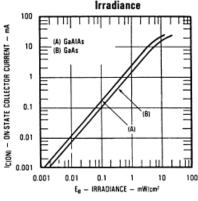
Coupling Characteristics



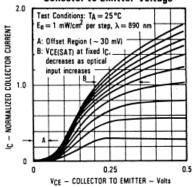
Normalized Collector Current vs. Angular Displacement



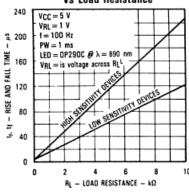
On-State Collector Current vs Irradiance



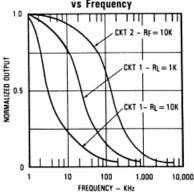
Normalized Collector Current vs Collector-to-Emitter Voltage



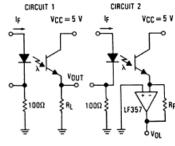
Rise and Fall Time vs Load Resistance



Normalized Output vs Frequency



Switching Time Test Circuit



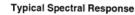
Test Conditions: Light source is pulsed LED with t_f and $t_f \le 500$ ns. IF is adjusted for VOUT = 1 Volt.

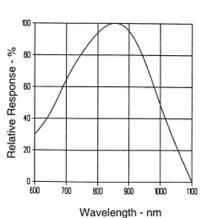
OP505, OP505W, OP506, OP506W OP535, OP705



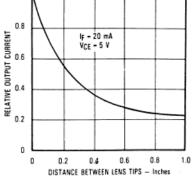
Performance

OP535A, OP535B, OP535D

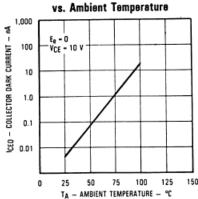




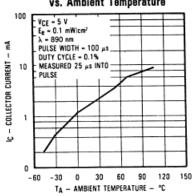
Coupling Characteristics of OP165 and OP535



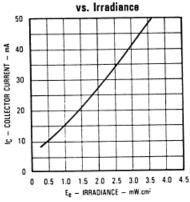
Collector Dark Current



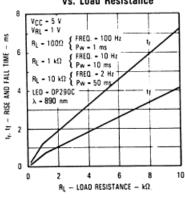
Collector Current vs. Ambient Temperature



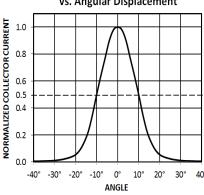
Collector Current



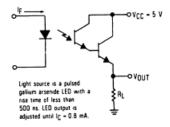
Rise and Fall Time vs. Load Resistance



Normalized Collector Current vs. Angular Displacement



Switching Time Test Circuit



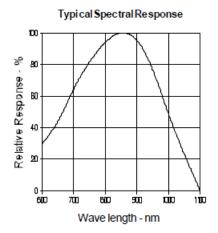
OP505, OP505W, OP506, OP506W OP535, OP705



Performance

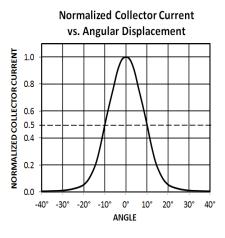
OP705A

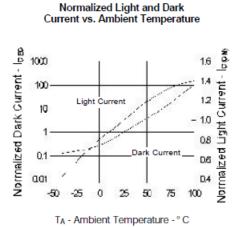
Schematic

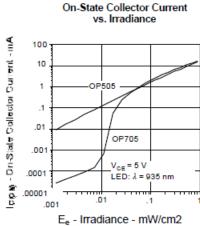


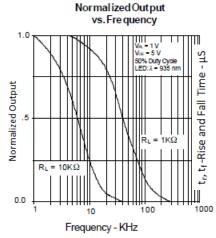
Collector

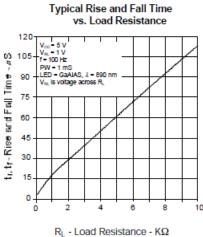
Emitter

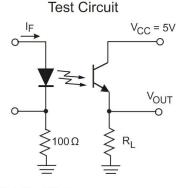












Switching Time

Test Conditions: Light Source is pulsed LED with tr and tf ≤ 500nS. IF is adjusted for V_{OUT} = 1Volt.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

TT Electronics:

<u>OP506A OP505A OP506B OP505B OP505C OP505D OP505W OP506C OP506D OP506W OP535A</u>
OP535B OP535C OP705A OP705B OP705C OP705D